

INFORMATION
DISCLOSURE
CITATION FORM FOR
PATENT APPLICATION
(FORM PTO - 1449)

Docket No.: 3536 C01

Serial No.: 09/775,173

Applicant(s): JAMES CARDUCCI, ET AL.

Filing Date: 01-31-01

Group: ~~1500~~ (763)RECEIVED
MAY 21 2001
TC 1700

U. S. PATENTS

Initials	Patent No	Issue Date	Name	COPIES	STATUS	FILED DATE
<i>gag</i>	5,401,351	03-28-95	SAMUKAWA			
	5,421,891	06-06-95	CAMPBELL ET AL.			
	5,429,070	07-04-95	CAMPBELL ET AL.			
	5,484,485	01-16-96	CHAPMAN			
	5,556,501	09-17-96	COLLINS ET AL.			
	5,662,819	09-02-97	KADOMURA			
	6,030,486	02-29-00	LOEWENHARDT, ET AL.			
<i>gag</i>	6,054,013	04-25-00	COLLINS, ET AL.			

FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Translation? (Yes/No/n/a)

Initials	Other Documents (Title, Author, Date, Pages, Etc., if known)
<i>gag</i>	U.S. Patent Application Serial No. 09/263,001, Filed March 5, 1999, entitled, "Magnetically Enhanced Inductively Coupled Plasma Reactor with Magnetically Confined Plasma," by Gerald Yin, et al.
	U.S. Patent Application Serial No. 09/521,799, Filed March 9, 2000, entitled, "Magnetically Enhanced Inductively Coupled Plasma Reactor with Magnetically Confined Plasma," by Gerald Yin, et al.
<i>gag</i>	U.S. Patent Application Serial No. 09/773, 409, Filed January 31, 2001, entitled, "Magnetically Enhanced Inductively Coupled Plasma Reactor with Magnetically Confined Plasma," by Peter Loewenhardt, et al.

Examiner's Signature:

George Goudreau

Date Considered:

9-031

Initial if reference was considered, whether or not citation with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).



INFORMATION DISCLOSURE CITATION FORM FOR PATENT APPLICATION (FORM PTO - 1449)	Docket No.: 3536 C01 Serial No.: 09/775,173
	Applicant(s): JAMES CARDUCCI, ET AL.
	Filing Date: 01-31-01 Group: 1763 1763

U. S. PATENTS

Initials	Patent No	Issue Date	Name	Class	Subclass	Filing Date

RECEIVED
MAY 17 2001
TC 1700

FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Translation? (Yes/No/NA)
GAG	HEI 8-264515	11.10.96	JAPAN	MITSUYOSHI IMAFUKU ET AL.	NA

Initials	Other Documents (Title, Author, Date, Pages, Etc., if known)
----------	--

Examiner's Signature: George Goudreau	Date Considered: 9-031
---------------------------------------	------------------------

Initial if reference was considered, whether or not citation with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).

INFORMATION
DISCLOSURE
CITATION FORM FOR
PATENT APPLICATION
(FORM PTO - 1449)

Docket No.: 3536 C01

Serial No.: 09/775,173

Applicant(s): JAMES CARDUCCI, ET AL.

Filing Date: 01-31-01

Group: ~~1763~~ 1763

U. S. PATENTS

Initials	Patent No	Issue Date	Name	Class	Subclass	Filing Date
gag	4,438,723	03-27-84	CANNELLA ET AL.			
	4,440,107	04-03-84	DOEHLER ET AL.			
	4,483,737	11-20-84	MANTEI			
	4,810,935	03-07-89	BOSWELL			
	4,842,707	06-27-89	KINOSHITA			
	4,990,229	02-05-91	CAMPBELL ET AL.			
	4,993,361	02-19-91	UNVALA			
	5,091,049	02-25-92	CAMPBELL ET AL.			
	5,122,251	06-16-92	CAMPBELL ET AL.			
	5,160,398	11-03-92	YANAGIDA			
	5,178,739	01-12-93	BARNES ET AL.			
	5,224,441	07-06-93	FELTS ET AL.			
gag	5,346,579	09-13-94	COOK ET AL.			

FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Class
gag	EP 0 173 583	05.03.86	EUROPE	KIM KUYNGSHIK ET AL.	
	EP 0 651 425	03.05.95	EUROPE	ROBERT CHAPMAN	
	EP 0 786 794	03.07.97	EUROPE	PETER LOEWENHARDT ET AL.	
gag	7-22389	24.01.95	JAPAN	YUTAKA KAKCHI ET AL.	

Initials

Other Documents (Title, Author, Date, Pages, Etc., if known)

Quick, A.K., Chen, R.T.S., and Hershkovitz, N., "Etch rate and plasma density radial uniformity measurements in a cusped field helicon plasma etcher," *J. Vac. Sci. Technol.*, Vol. 14, No. 3, May/June 1996, pp. 1041-1045.

Examiner's Signature:

George Gaudreau

Date Considered:

9-03'

Initial if reference was considered, whether or not citation with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).

INFORMATION
DISCLOSURE
CITATION FORM FOR
PATENT APPLICATION
(FORM PTO - 1449)

Docket No.: 3536 C01

Serial No.: 09/775,173

Applicant(s): JAMES CARDUCCI, ET AL.

Filing Date: 01-31-01

Group: ~~1763~~ 1763

U. S. PATENTS

Initials	Patent No	Issue Date	Name	Class	Subclass	Filing Date
GAJ	6,074,518 ✓	06-13-00	IMAFUKU ET AL.	156	345	01-04-99
GAJ	6,189,484 ✓	02-20-01	YIN ET AL.	118	723	03-05-99

RECEIVED
JUN 11 2001
TECHNOLOGY CENTER 1700

FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Translation? (Yes/No/n/a)

Initials Other Documents (Title, Author, Date, Pages, Etc., if known)

Examiner's Signature:

George Goudreau

Date Considered:

9-031

Initial if reference was considered, whether or not citation with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).